

## List of Publications by Year in descending order

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#	ARTICLE	IF	CITATIONS
1	The latest process and challenges of microwave dielectric ceramics based on pseudo phase diagrams. <i>Journal of Advanced Ceramics</i> , 2021, 10, 885-932.	8.9	115
2	Structural Evolution and Microwave Dielectric Properties of $(1-x)Zn_{0.5}Ti_{0.5}NbO_4-(1-x)Zn_{0.15}Nb_{0.3}Ti_{0.55}O_4$ Ceramics. <i>Inorganic Chemistry</i> , 2018, 57, 8264-8275.	8.0	95
3	Improved dielectric breakdown strength and energy storage properties in Er <sub>2</sub> O <sub>3</sub> modified Sr <sub>0.35</sub> Bi <sub>0.35</sub> K <sub>0.25</sub> TiO <sub>3</sub> . <i>Chemical Engineering Journal</i> , 2021, 403, 126290.	6.6	96
4	Usage of Valence bond theory in studying the structural/property regulation of microwave dielectric ceramics: a review. <i>Inorganic Chemistry Frontiers</i> , 2020, 7, 4711-4753.	3.0	95
5	Crystal Chemistry, Raman Spectra, and Bond Characteristics of Trirutile-Type $Co_{0.5}Ti_{0.5}TaO_4$ Microwave Dielectric Ceramics. <i>Inorganic Chemistry</i> , 2019, 58, 968-976.	1.9	88
6	Enhanced energy storage and fast charge-discharge properties of $(1-x)BaTiO_3-xBi(Ni_{1/2}Sn_{1/2})O_3$ relaxor ferroelectric ceramics. <i>Ceramics International</i> , 2019, 45, 17580-17590.	2.3	80
7	Aliovalent Doping Engineering for A- and B-Sites with Multiple Regulatory Mechanisms: A Strategy to Improve Energy Storage Properties of $Sr_{0.7}Bi_{0.2}TiO_3$ -Based Lead-Free Relaxor Ferroelectric Ceramics. <i>ACS Applied Materials &amp; Interfaces</i> , 2021, 13, 24833-24855.	4.0	79
8	A new type of BaTiO <sub>3</sub> -based ceramics with Bi(Mg <sub>1/2</sub> Sn <sub>1/2</sub> )O <sub>3</sub> modification showing improved energy storage properties and pulsed discharging performances. <i>Journal of Alloys and Compounds</i> , 2020, 819, 153004.	2.8	76
9	Structure, dielectric and relaxor properties of Sr <sub>0.7</sub> Bi <sub>0.2</sub> TiO <sub>3</sub> K <sub>0.5</sub> Bi <sub>0.5</sub> TiO <sub>3</sub> lead-free ceramics for energy storage applications. <i>Journal of Materiomics</i> , 2021, 7, 195-207.	2.8	62
10	Structure and microwave dielectric properties of the $Li_{2/3}(1-x)Sn_{1/3}(1-x)Mg_xO$ systems ( $x=0.4/7$ ). <i>Journal of the American Ceramic Society</i> , 2018, 101, 252-264.	1.9	59
11	Intrinsic dielectric properties of columbite $ZnNb_2O_6$ ceramics studied by Valence bond theory and Infrared spectroscopy. <i>Journal of the American Ceramic Society</i> , 2019, 102, 5365-5374.	1.9	58
12	Structural dependence of microwave dielectric properties of spinel structured $Mg_2(Ti_{1-x}Sn_x)O_4$ solid solutions: Crystal structure refinement, Raman spectra study and complex chemical bond theory. <i>Ceramics International</i> , 2019, 45, 11639-11647.	2.3	54
13	Synthesis and characterization of aerogel-like mesoporous nickel oxide for electrochemical supercapacitors. <i>Journal of Porous Materials</i> , 2006, 13, 407-412.	1.3	53
14	Crystal structure, Raman spectroscopy and microwave dielectric properties of $Ba_{3.75}Nd_{9.5}Ti_{18}-(Al_{1/2}Nb_{1/2})O_{54}$ ceramics. <i>Journal of Alloys and Compounds</i> , 2017, 723, 580-588.	2.8	49
15	Structural evolution and microwave dielectric properties of a novel $Li_3Mg_{2x}Nb_{1-x}Ti_xO_6$ system with a rock salt structure. <i>Inorganic Chemistry Frontiers</i> , 2018, 5, 3113-3125.	3.0	43
16	Phase evolution, structure and microwave dielectric properties of $Li_2+Mg_3SnO_6$ ( $x = 0.00-0.12$ ) ceramics. <i>Ceramics International</i> , 2017, 43, 13645-13652.	2.3	42
17	Structure, bond characteristics and Raman spectra of $CaMg_{1-x}Mn_xSi_2O_6$ microwave dielectric ceramics. <i>Ceramics International</i> , 2019, 45, 14160-14166.	2.3	41
18	Vibrational spectroscopic and crystal chemical analyses of double perovskite $Y_2MgTiO_6$ microwave dielectric ceramics. <i>Journal of the American Ceramic Society</i> , 2020, 103, 1121-1130.	1.9	37

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19	Effects of Li <sub>2</sub> O-B <sub>2</sub> O <sub>3</sub> -SiO <sub>2</sub> glass on the low-temperature sintering of Zn <sub>0.15</sub> Nb <sub>0.3</sub> Ti <sub>0.55</sub> O <sub>2</sub> ceramics. <i>Ceramics International</i> , 2018, 44, 8072-8080.	2.3	35
20	Gd <sub>2</sub> Zr <sub>3</sub> (MoO <sub>4</sub> ) <sub>9</sub> microwave dielectric ceramics with trigonal structure for LTCC application. <i>Journal of the American Ceramic Society</i> , 2020, 103, 1131-1139.	1.9	35
21	Microstructure and microwave dielectric properties of Na <sub>1/2</sub> Sm <sub>1/2</sub> TiO <sub>3</sub> filled PTFE, an environmental friendly composites. <i>Applied Surface Science</i> , 2018, 436, 900-906.	3.1	34
22	Correlation between structures and microwave dielectric properties of Ba <sub>3.75</sub> Nd <sub>9.5</sub> -Sm Ti <sub>17.5</sub> (Cr <sub>1/2</sub> Nb <sub>1/2</sub> ) <sub>0.5</sub> O <sub>54</sub> ceramics. <i>Journal of Alloys and Compounds</i> , 2018, 740, 492-499.	2.8	34
23	Effect of Ca/Si ratio on the microstructures and properties of CaO-B <sub>2</sub> O <sub>3</sub> -SiO <sub>2</sub> glass-ceramics. <i>Journal of Materials Science: Materials in Electronics</i> , 2009, 20, 262-266.	1.1	33
24	Relaxor Nature and Energy Storage Properties of Sr <sub>2</sub> M <sub>3</sub> NaNb <sub>5</sub> Ti <sub>15</sub> O <sub>32</sub> (M = La <sup>3+</sup> and Ho <sup>3+</sup> ) Tungsten Bronze Ceramics. <i>ACS Sustainable Chemistry and Engineering</i> , 2020, 8, 17527-17539.	3.2	32
25	Influence of Li-B-Si Additions on the Sintering and Microwave Dielectric Properties of Ba-Nd-Ti Ceramics. <i>Journal of Electronic Materials</i> , 2013, 42, 3519-3523.	1.0	31
26	Low Temperature Sintering Kinetics and Microwave Dielectric Properties of BaTi <sub>5</sub> O <sub>11</sub> Ceramic. <i>ACS Sustainable Chemistry and Engineering</i> , 2017, 5, 10606-10613.	3.2	29
27	Effects of (Cr <sub>0.5</sub> Ta <sub>0.5</sub> ) <sub>4+</sub> on structure and microwave dielectric properties of Ca <sub>0.61</sub> Nd <sub>0.26</sub> TiO <sub>3</sub> ceramics. <i>Ceramics International</i> , 2018, 44, 7771-7779.	2.3	28
28	Structural and dielectric relaxor properties of (1-x)BaTiO <sub>3</sub> -xBi(Zn <sub>1/2</sub> Zr <sub>1/2</sub> )O <sub>3</sub> ceramics for energy storage applications. <i>Journal of Materials Science: Materials in Electronics</i> , 2019, 30, 2772-2782.	1.1	26
29	Low-temperature sintering mechanism and microwave dielectric properties of ZnAl <sub>2</sub> O <sub>4</sub> -LMZBS composites. <i>Journal of Alloys and Compounds</i> , 2019, 797, 744-753.	2.8	25
30	Preparation of BaTiO <sub>3</sub> -based ceramics by nanocomposite doping process. <i>Journal of Materials Science</i> , 2007, 42, 2090-2096.	1.7	24
31	Effect of CaO content on structure and properties of low temperature co-fired glass-ceramic in the Li <sub>2</sub> O-Al <sub>2</sub> O <sub>3</sub> -SiO <sub>2</sub> system. <i>Journal of Materials Science: Materials in Electronics</i> , 2016, 27, 2455-2459.	1.1	23
32	Excellent thermal stability and energy storage properties of lead-free Bi <sub>0.5</sub> Na <sub>0.5</sub> TiO <sub>3</sub> -based ceramic. <i>Journal of the American Ceramic Society</i> , 2022, 105, 4027-4038.	1.9	23
33	A new low-firing and high-Q microwave dielectric ceramic Li <sub>9</sub> Zr <sub>3</sub> NbO <sub>13</sub> . <i>Journal of the American Ceramic Society</i> , 2018, 101, 2202-2207.	1.9	22
34	Relationships between Sn substitution for Ti and microwave dielectric properties of Mg <sub>2</sub> (Ti <sub>1-x</sub> Sn <sub>x</sub> )O <sub>4</sub> ceramics system. <i>Journal of Materials Science: Materials in Electronics</i> , 2015, 26, 571-577.	1.1	21
35	Structure stability, bond characteristics and microwave dielectric properties of co-substituted NdNbO <sub>4</sub> ceramics. <i>Ceramics International</i> , 2019, 45, 3620-3626.	2.3	21
36	Crystal structure, microwave dielectric properties and low temperature sintering of (Al <sub>0.5</sub> Nb <sub>0.5</sub> ) <sub>4+</sub> co-substitution for Ti <sub>4+</sub> of LiNb <sub>0.6</sub> Ti <sub>0.5</sub> O <sub>3</sub> ceramics. <i>Ceramics International</i> , 2019, 45, 5418-5424.	2.3	21

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37	Synthesis of CaAl <sub>2</sub> B <sub>2</sub> O <sub>4</sub> +3: Novel microwave dielectric ceramics with low permittivity and low loss. Journal of the European Ceramic Society, 2021, 41, 2596-2601.	2.8	20
38	Thermal and dielectric properties of the LTCC composites based on the eutectic system BaO-Al <sub>2</sub> O <sub>3</sub> -SiO <sub>2</sub> -B <sub>2</sub> O <sub>3</sub> . Journal of Materials Science: Materials in Electronics, 2011, 22, 238-243.	1.1	19
39	Effects of MgO on properties of Li <sub>2</sub> O-Al <sub>2</sub> O <sub>3</sub> -SiO <sub>2</sub> glass-ceramics for LTCC applications. Journal of Materials Science: Materials in Electronics, 2014, 25, 2149-2154.	1.1	19
40	Effects of perfluorooctyltriethoxysilane coupling agent on the properties of silica filled PTFE composites. Journal of Materials Science: Materials in Electronics, 2017, 28, 8810-8817.	1.1	19
41	Investigations of dielectric properties of wolframite A <sub>0.5</sub> Zr <sub>0.5</sub> NbO <sub>4</sub> ceramics by bond theory and far-infrared spectroscopy. Ceramics International, 2020, 46, 3688-3694.	2.3	19
42	Novel lead-free (1-x)Sr <sub>0.7</sub> Bi <sub>0.2</sub> Ti <sub>0.3</sub> -xLa(Mg <sub>0.5</sub> Zr <sub>0.5</sub> )O <sub>3</sub> energy storage ceramics with high charge-discharge and excellent temperature-stable dielectric properties. Ceramics International, 2021, 47, 26215-26223.	2.3	19
43	Influence of SiO <sub>2</sub> Addition on Properties of PTFE/TiO <sub>2</sub> Microwave Composites. Journal of Electronic Materials, 2018, 47, 633-640.	1.0	18
44	Effect of sintering temperature on the crystallization behavior and properties of silica filled PTFE composites. Journal of Materials Science: Materials in Electronics, 2016, 27, 13288-13293.	1.1	17
45	Microwave dielectric properties of (1-x)(Ba <sub>3.75</sub> Nd <sub>9.5</sub> Cr <sub>0.25</sub> Nb <sub>0.25</sub> Ti <sub>17.5</sub> O <sub>54</sub> ) <sub>1-x</sub> ceramics. Journal of the American Ceramic Society, 2017, 100, 4058-4065.		
46	EFFECTS OF ELECTRODEPOSITION CONDITIONS ON THE MICROSTRUCTURES OF ZNO THIN FILMS. Integrated Ferroelectrics, 2007, 88, 33-43.	0.3	16
47	Low-firing, temperature stable and improved microwave dielectric properties of ZnO TiO <sub>2</sub> Nb <sub>2</sub> O <sub>5</sub> composite ceramics. Journal of Materiomics, 2019, 5, 471-479.	2.8	16
48	Low-temperature processing and microwave dielectric properties of LB glass-doped Ba <sub>3.75</sub> Nd <sub>9.5</sub> Ti <sub>17.5</sub> (Cr <sub>0.5</sub> Nb <sub>0.5</sub> ) <sub>0.5</sub> O <sub>54</sub> ceramic. Journal of the American Ceramic Society, 2021, 104, 1726-1739.		
49	Effects of ZrO <sub>2</sub> substitution on crystal structure and microwave dielectric properties of Zn <sub>0.15</sub> Nb <sub>0.3</sub> (Ti <sub>1</sub> -Zr) <sub>0.55</sub> O <sub>2</sub> ceramics. Ceramics International, 2018, 44, 22710-22717.	2.3	15
50	Dependence of microwave dielectric properties on site substitution in Ba <sub>3.75</sub> Nd <sub>9.5</sub> Ti <sub>18</sub> O <sub>54</sub> ceramic. Journal of Materials Science: Materials in Electronics, 2016, 27, 10951-10957.	1.1	14
51	Bond characteristics, vibrational spectrum and optimized microwave dielectric properties of chemically substituted NdNbO <sub>4</sub> . Ceramics International, 2019, 45, 16940-16947.	2.3	14
52	Enhanced thermal and mechanical properties of Li-Al-Si composites with K <sub>2</sub> O-B <sub>2</sub> O <sub>3</sub> -SiO <sub>2</sub> glass for LTCC application. Ceramics International, 2019, 45, 15654-15659.	2.3	14
53	The effect of doping process on microstructure and dielectric properties of BaTiO <sub>3</sub> -based X7R materials. Journal of Materials Science: Materials in Electronics, 2004, 15, 601-606.	1.1	13
54	Influence of 3d-elements on dielectric properties of BaTiO <sub>3</sub> ceramics. Journal of Materials Science: Materials in Electronics, 2005, 16, 669-672.	1.1	13

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55	Influence of Al <sub>2</sub> O <sub>3</sub> /SiO <sub>2</sub> ratio on the microstructure and properties of low temperature co-fired CaO-Al <sub>2</sub> O <sub>3</sub> -SiO <sub>2</sub> based ceramics. Journal of Materials Science: Materials in Electronics, 2014, 25, 4206-4211.	1.1	13
56	Synthesis and study of lithium silicate glass-ceramic. Journal of Materials Science: Materials in Electronics, 2017, 28, 15405-15410.	1.1	13
57	Stabilizing temperature-capacitance dependence of (Sr, Pb) Tj ETQq1 1 0.784314 rgBT /Overlock 10 Tf 50 667 Td (Bi)TiO <sub>3</sub> Journal of the American Ceramic Society, 2019, 102, 4029-4037.	1.9	13
58	The effect of Mn addition on phase development, microstructure and microwave dielectric properties of ZrTi <sub>2</sub> O <sub>6</sub> -ZnNb <sub>2</sub> O <sub>6</sub> ceramics. Materials Letters, 2012, 80, 124-126.	1.3	12
59	Different Additives Doped Ca-Nd-Ti Microwave Dielectric Ceramics with Distorted Oxygen Octahedrons and High Q-Value. ACS Omega, 2018, 3, 11033-11040.	1.6	12
60	Influence of Mg <sub>2</sub> SiO <sub>4</sub> addition on crystal structure and microwave properties of Mg <sub>2</sub> Al <sub>4</sub> Si <sub>5</sub> O <sub>18</sub> ceramic system. Journal of Materials Science: Materials in Electronics, 2018, 29, 17967-17973.	1.1	12
61	Effect of Zn <sup>2+</sup> substitution for Mg <sup>2+</sup> in Li <sub>3</sub> Mg <sub>2</sub> SbO <sub>6</sub> and the impact on the bond characteristics and microwave dielectric properties. Journal of Alloys and Compounds, 2020, 832, 155043.	2.8	12
62	Influence of sintering atmosphere on the microstructure and electrical properties of BaTiO <sub>3</sub> -based X8R materials. Journal of Materials Science, 2006, 41, 1813-1817.	1.7	11
63	Microstructure and properties of ZnO doped CaO-Al <sub>2</sub> O <sub>3</sub> -SiO <sub>2</sub> ceramic for LTCC applications. Journal of Materials Science: Materials in Electronics, 2015, 26, 1512-1517.	1.1	11
64	Phase transitions and electrical properties in La <sup>3+</sup> -substituted Bi <sub>0.5</sub> (Na <sub>0.75</sub> K <sub>0.15</sub> Li <sub>0.10</sub> ) <sub>0.5</sub> TiO <sub>3</sub> ceramics. Journal of Materials Science, 2006, 41, 565-567.	1.7	10
65	Microstructures and dielectric properties of Y/Zn codoped BaTiO <sub>3</sub> ceramics. Journal of Materials Science, 2007, 42, 5223-5228.	1.7	10
66	Low temperature preparation of the Zn <sub>2</sub> SiO <sub>4</sub> ceramics with the addition of BaO and B <sub>2</sub> O <sub>3</sub> . Journal of Materials Science: Materials in Electronics, 2011, 22, 1274-1281.	1.1	10
67	The size-effect of Al <sub>2</sub> O <sub>3</sub> on the sinterability, microstructure and properties of glass-alumina composites. Glass Physics and Chemistry, 2015, 41, 503-508.	0.2	10
68	Preparation and properties of low temperature sintered CaO-B <sub>2</sub> O <sub>3</sub> -SiO <sub>2</sub> microwave dielectric ceramics using the solid-state reaction. Materials Science-Poland, 2013, 31, 404-409.	0.4	9
69	Microstructures and Microwave Dielectric Properties of Na <sub>0.5</sub> Nd <sub>0.2</sub> Sm <sub>0.3</sub> Ti <sub>1-x</sub> Sn <sub>x</sub> O <sub>3</sub> Ceramics (x=0.00 to 0.50). Journal of Electronic Materials, 2015, 44, 4236-4242.	1.0	9
70	Sintering characteristic and microwave dielectric properties of 0.45Ca <sub>0.6</sub> Nd <sub>0.267</sub> Ti <sub>0.3</sub> -0.55Li <sub>0.5</sub> Nd <sub>0.5</sub> TiO <sub>3</sub> ceramics with La <sub>2</sub> O <sub>3</sub> -B <sub>2</sub> O <sub>3</sub> -ZnO additive. Applied Physics A: Materials Science and Processing, 2018, 124, 1.	1.1	9
71	Effects of (Na <sub>1/2</sub> Nd <sub>1/2</sub> )TiO <sub>3</sub> on the microstructure and microwave dielectric properties of PTFE/ceramic composites. Journal of Materials Science: Materials in Electronics, 2018, 29, 20680-20687.	1.1	9
72	Microwave dielectric properties of Li <sub>2</sub> O-MgO-ZnO-B <sub>2</sub> O <sub>3</sub> -SiO <sub>2</sub> glass-ceramics (x = 30-50 wt.%). Journal of the Ceramic Society of Japan, 2018, 126, 163-169.	1.1	9

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73	Domain Structure and Fatigue Behavior of La <sup>3+</sup> -Doped SrBi <sub>2</sub> Ta <sub>2</sub> O <sub>9</sub> Thin Films. Journal of the American Ceramic Society, 2005, 88, 85-88.	1.9	8
74	Microwave Dielectric Properties of Aluminum-Substituted Ba <sub>6</sub> Y <sub>3</sub> Nd <sub>8</sub> Ti <sub>18</sub> O <sub>54</sub> Ceramics. International Journal of Applied Ceramic Technology, 2016, 13, 564-568.	1.1	8
75	Preparation, characterization and properties of FEP modified PTFE/glass fiber composites for microwave circuit application. Journal of Materials Science: Materials in Electronics, 2017, 28, 6015-6021.	1.1	8
76	Newly developed polytetrafluoroethylene composites based on F8261-modified Li <sub>2</sub> Mg <sub>2.88</sub> Ca <sub>0.12</sub> TiO <sub>6</sub> powder. Journal of Alloys and Compounds, 2019, 803, 145-152.	2.8	7
77	FABRICATION OF PZT THIN FILMS WITH TiO <sub>x</sub> BUFFER LAYERS BY RF MAGNETRON SPUTTERING. Integrated Ferroelectrics, 2006, 80, 281-288.	0.3	6
78	Study on the physics and dielectric property of Al <sub>2</sub> O <sub>3</sub> -B <sub>2</sub> O <sub>3</sub> -SiO <sub>2</sub> /Al <sub>2</sub> O <sub>3</sub> glass-ceramic. Journal of Materials Science: Materials in Electronics, 2016, 27, 12654-12659.	1.1	6
79	Effects of Zr-Substitution on Microwave Dielectric Properties of Na <sub>0.5</sub> Nd <sub>0.2</sub> Sm <sub>0.3</sub> Ti <sub>1-x</sub> Zr <sub>x</sub> O <sub>3</sub> Ceramics (x=0.00-0.30). Journal of Electronic Materials, 2016, 45, 5198-5205.	1.0	6
80	Influence of CaTiO <sub>3</sub> doping on the microwave dielectric properties of Li <sub>2</sub> MgTiO <sub>4</sub> ceramics. Journal of Materials Science: Materials in Electronics, 2018, 29, 643-649.	1.1	6
81	Research on hydrophobicity treatment of aluminum nitride powder and the fabrication and characterization of AlN/PTFE composite substrates. Journal of Materials Science: Materials in Electronics, 2018, 29, 14890-14896.	1.1	6
82	Improved Microwave Dielectric Properties of LiNb <sub>0.6</sub> Ti <sub>0.5</sub> O <sub>3</sub> Ceramics with Zr Substitutions. Journal of Electronic Materials, 2019, 48, 5080-5087.	1.0	6
83	Fabrication and properties of Li <sub>2</sub> O-Al <sub>2</sub> O <sub>3</sub> -SiO <sub>2</sub> glass/Al <sub>2</sub> O <sub>3</sub> composites for low temperature co-fired ceramic applications. Journal of Materials Science: Materials in Electronics, 2015, 26, 1789-1794.	1.1	5
84	Crystallization, microstructures and properties of low temperature co-fired CaO-Al <sub>2</sub> O <sub>3</sub> -SiO <sub>2</sub> glass-ceramic. Journal of Electroceramics, 2016, 37, 145-150.	0.8	5
85	A new niobate-based CaO-CuO-Nb <sub>2</sub> O <sub>5</sub> microwave dielectric ceramic composite for LTCC applications. Journal of Materials Science: Materials in Electronics, 2018, 29, 4533-4537.	1.1	5
86	Dielectric and piezoelectric properties of (0.97-x) Bi <sub>1/2</sub> Na <sub>1/2</sub> TiO <sub>3</sub> -xBi <sub>1/2</sub> K <sub>1/2</sub> TiO <sub>3</sub> -0.03NaNbO <sub>3</sub> ceramics. Journal of Materials Science, 2006, 41, 3561-3567.	1.7	4
87	Preparation of the LTCC composite ceramics with low permittivity. Journal of Materials Science: Materials in Electronics, 2011, 22, 453-457.	1.1	4
88	Effects of Y <sub>2</sub> O <sub>3</sub> substitution on microwave dielectric properties of Ba(Co <sub>0.6</sub> Zn <sub>0.38</sub> ) <sub>1/3</sub> Nb <sub>2/3</sub> O <sub>3</sub> ceramics. Journal of Materials Science: Materials in Electronics, 2015, 26, 7683-7689.	1.1	4
89	Sintering behavior and microwave dielectric properties of TiO <sub>2</sub> added Ba <sub>4</sub> (Sm <sub>0.5</sub> Nd <sub>0.5</sub> ) <sub>28</sub> /3Ti <sub>18</sub> O <sub>54</sub> ceramics with K <sub>2</sub> O-B <sub>2</sub> O <sub>3</sub> -SiO <sub>2</sub> glass. Journal of Materials Science: Materials in Electronics, 2016, 27, 2783-2788.	1.1	4
90	Investigation of Low-Temperature Sintering Mechanism on Ba <sub>0.5</sub> Nd <sub>0.5</sub> Ti <sub>0.5</sub> O <sub>3</sub> Dielectric Ceramics with Li <sub>2</sub> O-B <sub>2</sub> O <sub>3</sub> -SiO <sub>2</sub> and Ba <sub>0.5</sub> Zn <sub>0.5</sub> Ti <sub>0.5</sub> O <sub>3</sub> Glasses. Physica Status Solidi (A) Applications and Materials Science, 2018, 215, 1700938.	0.8	4

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91	Structure, phase composition, Raman spectra, and microwave dielectric properties of novel Co <sub>0.5</sub> Zr <sub>0.5</sub> TaO <sub>4</sub> ceramics. <i>Ceramics International</i> , 2019, 45, 15445-15450.	2.3	4
92	Influence of Li <sub>2</sub> O-MgO-ZnO-B <sub>2</sub> O <sub>3</sub> -SiO <sub>2</sub> glass doping on the microwave dielectric properties and sintering temperature of Li <sub>3</sub> Mg <sub>2</sub> NbO <sub>6</sub> ceramics. <i>Journal of Materials Science: Materials in Electronics</i> , 2020, 31, 17029-17035.	1.1	4
93	Investigation of the crystal structure and electrical properties of La <sup>3+</sup> -doped SrBi <sub>2</sub> Ta <sub>2</sub> O <sub>9</sub> ceramics. <i>Journal of Materials Science: Materials in Electronics</i> , 2003, 14, 229-231.	1.1	3
94	The Study of Ferroelectric La-Doped PbTiO <sub>3</sub> Thin Films Prepared by RF Magnetron Sputtering. <i>Integrated Ferroelectrics</i> , 2003, 52, 223-228.	0.3	3
95	Impacts of Al <sub>2</sub> O <sub>3</sub> Doping on Microstructure, Phase Constitution and Microwave Dielectric Properties of Ca <sub>0.61</sub> Nd <sub>0.26</sub> TiO <sub>3</sub> Ceramics. <i>Transactions of the Indian Ceramic Society</i> , 2017, 76, 97-101.	0.4	3
96	Structure and microwave dielectric properties of Zn <sub>0.9</sub> Mg <sub>0.1</sub> TiO <sub>3</sub> -Zn <sub>0.15</sub> Nb <sub>0.3</sub> Ti <sub>0.55</sub> O <sub>2</sub> ceramics with ZnO-B <sub>2</sub> O <sub>3</sub> -SiO <sub>2</sub> glass. <i>Journal of Materials Science: Materials in Electronics</i> , 2018, 29, 11901-11909.	1.1	3
97	Low-temperature sintering kinetics and dielectric properties of Ba <sub>5</sub> Nb <sub>4</sub> O <sub>15</sub> with B <sub>2</sub> O <sub>3</sub> -SiO <sub>2</sub> glass. <i>Journal of Materials Science: Materials in Electronics</i> , 2021, 32, 8716-8724.	1.1	3
98	Improvement of microwave dielectric characteristics in SrNdAlO <sub>4</sub> ceramics by La-substitution. <i>Journal of Materials Science: Materials in Electronics</i> , 2016, 27, 11634-11639.	1.1	2
99	A Temperature-Insensitive Ba <sub>3.75</sub> Nd <sub>9.5</sub> Ti <sub>17.5</sub> (Cr <sub>0.5</sub> Nb <sub>0.5</sub> ) <sub>0.5</sub> O <sub>54</sub> Microwave Dielectric Ceramic by Bi <sup>3+</sup> Substitution. <i>Journal of Electronic Materials</i> , 2017, 46, 1230-1234.	1.0	2
100	Properties and crystallization kinetics of low temperature co-fired Li <sub>2</sub> O-Al <sub>2</sub> O <sub>3</sub> -SiO <sub>2</sub> electroceramics. <i>Journal of Electroceramics</i> , 2018, 40, 316-322.	0.8	2
101	Thermal and microwave dielectric properties of Li-Si-based ceramics. <i>Ceramics International</i> , 2021, 47, 17693-17701.	2.3	2
102	Tailoring sintering kinetics and dielectric properties of Li <sub>2</sub> SiO <sub>3</sub> ceramics by CaO-B <sub>2</sub> O <sub>3</sub> -SiO <sub>2</sub> glass dopant for LTCC substrate applications. <i>Journal of Materials Science: Materials in Electronics</i> , 2022, 33, 4043-4050.	1.1	2
103	Effects of complex dopants on the microstructure and dielectric properties of BCTZ ceramics. <i>Journal of Materials Science: Materials in Electronics</i> , 2005, 16, 257-261.	1.1	1
104	Effect of SrTiO <sub>3</sub> on the properties of CBS glasses/Al <sub>2</sub> O <sub>3</sub> ceramics. <i>Journal of Materials Science: Materials in Electronics</i> , 2016, 27, 6592-6597.	1.1	1
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